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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4/M0
Core Size	32-Bit Dual-Core
Speed	204MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, Microwire, SD, SPI, SSI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, Motor Control PWM, POR, PWM, WDT
Number of I/O	83
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	16K x 8
RAM Size	104K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 8x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc4313jbd144e

4.1 Ordering options

Table 2. Ordering options

Type number	Flash total	Flash bank A	Flash bank B	Total SRAM	LCD	Ethernet	USB0 (Host, Device, OTG)	USB1 (Host, Device)/ ULPI interface	Motor control PWM	QEI	ADC channels	Temperature range[1]	GPIO
LPC4357FET256	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	F	164
LPC4357JET256	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	164
LPC4357JBD208	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	142
LPC4353FET256	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	F	164
LPC4353JET256	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	164
LPC4353JBD208	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	142
LPC4337FET256	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	F	164
LPC4337JET256	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	J	164
LPC4337JBD144	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	no	8	J	83
LPC4337JET100	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/no	no	no	4	J	49
LPC4333FET256	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	F	164
LPC4333JET256	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	J	164
LPC4333JBD144	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	no	8	J	83
LPC4333JET100	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/no	no	no	4	J	49
LPC4327JBD144	1 MB	512 kB	512 kB	136 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4327JET100	1 MB	512 kB	512 kB	136 kB	no	no	yes	no/no	no	no	4	J	49
LPC4325JBD144	768 kB	384 kB	384 kB	136 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4325JET100	768 kB	384 kB	384 kB	136 kB	no	no	yes	no/no	no	no	4	J	49
LPC4323JBD144	512 kB	256 kB	256 kB	104 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4323JET100	512 kB	256 kB	256 kB	104 kB	no	no	yes	no/no	no	no	4	J	49
LPC4322JBD144	512 kB	512 kB	0 kB	104 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4322JET100	512 kB	512 kB	0 kB	104 kB	no	no	yes	no/no	no	no	4	J	49
LPC4317JBD144	1 MB	512 kB	512 kB	136 kB	no	no	no	no/no	yes	no	8	J	83
LPC4317JET100	1 MB	512 kB	512 kB	136 kB	no	no	no	no/no	no	no	4	J	49
LPC4315JBD144	768 kB	384 kB	384 kB	136 kB	no	no	no	no/no	yes	no	8	J	83
LPC4315JET100	768 kB	384 kB	384 kB	136 kB	no	no	no	no/no	no	no	4	J	49
LPC4313JBD144	512 kB	256 kB	256 kB	104 kB	no	no	no	no/no	yes	no	8	J	83
LPC4313JET100	512 kB	256 kB	256 kB	104 kB	no	no	no	no/no	no	no	4	J	49
LPC4312JBD144	512 kB	512 kB	0 kB	104 kB	no	no	no	no/no	yes	no	8	J	83
LPC4312JET100	512 kB	512 kB	0 kB	104 kB	no	no	no	no/no	no	no	4	J	49

[1] J = -40 °C to +105 °C; F = -40 °C to +85 °C.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P5_4	P9	-	80	57	[2]	N; PU	I/O	**GPIO2[13] —** General purpose digital input/output pin.
							O	**MCOB0 —** Motor control PWM channel 0, output B.
							I/O	**EMC_D8 —** External memory data line 8.
							-	**R —** Function reserved.
							I	**U1_CTS —** Clear to Send input for UART 1.
							O	**T1_MAT0 —** Match output 0 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_5	P10	-	81	58	[2]	N; PU	I/O	**GPIO2[14] —** General purpose digital input/output pin.
							O	**MCOA1 —** Motor control PWM channel 1, output A.
							I/O	**EMC_D9 —** External memory data line 9.
							-	**R —** Function reserved.
							I	**U1_DCD —** Data Carrier Detect input for UART 1.
							O	**T1_MAT1 —** Match output 1 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_6	T13	-	89	63	[2]	N; PU	I/O	**GPIO2[15] —** General purpose digital input/output pin.
							O	**MCOB1 —** Motor control PWM channel 1, output B.
							I/O	**EMC_D10 —** External memory data line 10.
							-	**R —** Function reserved.
							O	**U1_TXD —** Transmitter output for UART 1.
							O	**T1_MAT2 —** Match output 2 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_7	R12	-	91	65	[2]	N; PU	I/O	**GPIO2[7] —** General purpose digital input/output pin.
							O	**MCOA2 —** Motor control PWM channel 2, output A.
							I/O	**EMC_D11 —** External memory data line 11.
							-	**R —** Function reserved.
							I	**U1_RXD —** Receiver input for UART 1.
							O	**T1_MAT3 —** Match output 3 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P6_7	J13	-	123	85	[2]	N; PU	-	**R —** Function reserved.
							I/O	**EMC_A15 —** External memory address line 15.
							I/O	**SGPIO6 —** General purpose digital input/output pin.
							O	**USB0_IND1 —** USB0 port indicator LED control output 1.
							I/O	**GPIO5[15] —** General purpose digital input/output pin.
							O	**T2_MAT0 —** Match output 0 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_8	H13	-	125	86	[2]	N; PU	-	**R —** Function reserved.
							I/O	**EMC_A14 —** External memory address line 14.
							I/O	**SGPIO7 —** General purpose digital input/output pin.
							O	**USB0_IND0 —** USB0 port indicator LED control output 0.
							I/O	**GPIO5[16] —** General purpose digital input/output pin.
							O	**T2_MAT1 —** Match output 1 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_9	J15	F8	139	97	[2]	N; PU	I/O	**GPIO3[5] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_DYCS0}}$ —** SDRAM chip select 0.
							-	**R —** Function reserved.
							O	**T2_MAT2 —** Match output 2 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_10	H15	-	142	100	[2]	N; PU	I/O	**GPIO3[6] —** General purpose digital input/output pin.
							O	**$\overline{\text{MCABORT}}$ —** Motor control PWM, LOW-active fast abort.
							-	**R —** Function reserved.
							O	**EMC_DQMOUT1 —** Data mask 1 used with SDRAM and static devices.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PB_1	A14	-	175	-	[2]	N; PU	-	**R —** Function reserved.
							I	**USB1_ULPI_DIR —** ULPI link DIR signal. Controls the ULP data line direction.
							O	**LCD_VD22 —** LCD data.
							-	**R —** Function reserved.
							I/O	**GPIO5[21] —** General purpose digital input/output pin.
							O	**CTOUT_6 —** SCT output 6. Match output 2 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PB_2	B12	-	177	-	[2]	N; PU	-	**R —** Function reserved.
							I/O	**USB1_ULPI_D7 —** ULPI link bidirectional data line 7.
							O	**LCD_VD21 —** LCD data.
							-	**R —** Function reserved.
							I/O	**GPIO5[22] —** General purpose digital input/output pin.
							O	**CTOUT_7 —** SCT output 7. Match output 3 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PB_3	A13	-	178	-	[2]	N; PU	-	**R —** Function reserved.
							I/O	**USB1_ULPI_D6 —** ULPI link bidirectional data line 6.
							O	**LCD_VD20 —** LCD data.
							-	**R —** Function reserved.
							I/O	**GPIO5[23] —** General purpose digital input/output pin.
							O	**CTOUT_8 —** SCT output 8. Match output 0 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PB_4	B11	-	180	-	[2]	N; PU	-	**R —** Function reserved.
							I/O	**USB1_ULPI_D5 —** ULPI link bidirectional data line 5.
							O	**LCD_VD15 —** LCD data.
							-	**R —** Function reserved.
							I/O	**GPIO5[24] —** General purpose digital input/output pin.
							I	**CTIN_5 —** SCT input 5. Capture input 2 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PD_7	T6	-	72	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_5 —** SCT input 5. Capture input 2 of timer 2.
							I/O	**EMC_D21 —** External memory data line 21.
							-	**R —** Function reserved.
							I/O	**GPIO6[21] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							I/O	**SGPIO11 —** General purpose digital input/output pin.
PD_8	P8	-	74	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_6 —** SCT input 6. Capture input 1 of timer 3.
							I/O	**EMC_D22 —** External memory data line 22.
							-	**R —** Function reserved.
							I/O	**GPIO6[22] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							I/O	**SGPIO12 —** General purpose digital input/output pin.
PD_9	T11	-	84	-	[2]	N; PU	-	**R —** Function reserved.
							O	**CTOUT_13 —** SCT output 13. Match output 3 of timer 3.
							I/O	**EMC_D23 —** External memory data line 23.
							-	**R —** Function reserved.
							I/O	**GPIO6[23] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							I/O	**SGPIO13 —** General purpose digital input/output pin.
PD_10	P11	-	86	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_1 —** SCT input 1. Capture input 1 of timer 0. Capture input 1 of timer 2.
							O	**$\overline{\text{EMC\_BLS3}}$ —** LOW active Byte Lane select signal 3.
							-	**R —** Function reserved.
							I/O	**GPIO6[24] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PE_6	M16	-	124	-	[2]	N; PU	-	**R —** Function reserved.
							O	**CTOUT_2 —** SCT output 2. Match output 2 of timer 0.
							I	**U1_RI —** Ring Indicator input for UART 1.
							I/O	**EMC_D25 —** External memory data line 25.
							I/O	**GPIO7[6] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PE_7	F15	-	149	-	[2]	N; PU	-	**R —** Function reserved.
							O	**CTOUT_5 —** SCT output 5. Match output 3 of timer 3.
							I	**U1_CTS —** Clear to Send input for UART1.
							I/O	**EMC_D26 —** External memory data line 26.
							I/O	**GPIO7[7] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PE_8	F14	-	150	-	[2]	N; PU	-	**R —** Function reserved.
							O	**CTOUT_4 —** SCT output 4. Match output 3 of timer 3.
							I	**U1_DSR —** Data Set Ready input for UART 1.
							I/O	**EMC_D27 —** External memory data line 27.
							I/O	**GPIO7[8] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PE_9	E16	-	152	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_4 —** SCT input 4. Capture input 2 of timer 1.
							I	**U1_DCD —** Data Carrier Detect input for UART 1.
							I/O	**EMC_D28 —** External memory data line 28.
							I/O	**GPIO7[9] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
VSS	G9, H7, J10, J11, K8	C8, D4, D5, G8, J3, J6	-	-	[13]	-	-	Ground.
VSSIO	C4, D13, G6, G7, G8, H8, H9, J8, J9, K9, K10, M13, P7, P13	-	5, 56, 109, 157	4, 40, 76, 109	[13]	-	-	Ground.
VSSA	B2	C2	196	135		-	-	Analog ground.

[1] N = neutral, input buffer disabled; no extra VDDIO current consumption if the input is driven midway between supplies; set the EZI bit in the SFS register to enable the input buffer; I = input, OL = output driving LOW; OH = output driving HIGH; AI/O = analog input/output; IA = inactive; PU = pull-up enabled (weak pull-up resistor pulls up pin to VDDIO; F = floating. Reset state reflects the pin state at reset without boot code operation.

[2] 5 V tolerant pad with 15 ns glitch filter (5 V tolerant if VDDIO present; if VDDIO not present, do not exceed 3.6 V); provides digital I/O functions with TTL levels and hysteresis; normal drive strength.

[3] 5 V tolerant pad with 15 ns glitch filter (5 V tolerant if VDDIO present; if VDDIO not present, do not exceed 3.6 V); provides digital I/O functions with TTL levels, and hysteresis; high drive strength.

[4] 5 V tolerant pad with 15 ns glitch filter (5 V tolerant if VDDIO present; if VDDIO not present, do not exceed 3.6 V); provides high-speed digital I/O functions with TTL levels and hysteresis.

[5] 5 V tolerant pad providing digital I/O functions (with TTL levels and hysteresis) and analog input or output (5 V tolerant if VDDIO present; if VDDIO not present, do not exceed 3.6 V). When configured as a ADC input or DAC output, the pin is not 5 V tolerant and the digital section of the pad must be disabled by setting the pin to an input function and disabling the pull-up resistor through the pin's SFSP register.

[6] 5 V tolerant transparent analog pad.

[7] For maximum load C_L = 6.5 μF and maximum resistance R_{pd} = 80 kΩ, the VBUS signal takes about 2 s to fall from VBUS = 5 V to VBUS = 0.2 V when it is no longer driven.

[8] Transparent analog pad. Not 5 V tolerant.

[9] Pad provides USB functions; 5 V tolerant if VDDIO present; if VDDIO not present, do not exceed 3.6 V. It is designed in accordance with the USB specification, revision 2.0 (Full-speed and Low-speed mode only).

[10] Open-drain 5 V tolerant digital I/O pad, compatible with I2C-bus Fast Mode Plus specification. This pad requires an external pull-up to provide output functionality. When power is switched off, this pin connected to the I2C-bus is floating and does not disturb the I2C lines.

[11] 5 V tolerant pad with 20 ns glitch filter; provides digital I/O functions with open-drain output and hysteresis.

[12] VPP is internally connected to VDDIO for all packages with the exception of the LBGA256 package.

[13] On the LQFP208 package, VSSIO and VSS are connected to a common ground plane.

Remark: Any interrupt can wake up the ARM Cortex-M4 from sleep mode if enabled in the NVIC.

7.9 Global Input Multiplexer Array (GIMA)

The GIMA allows to route signals to event-driven peripheral targets like the SCTimer/PWM, timers, event router, or the ADCs.

7.9.1 Features

- Single selection of a source.
- Signal inversion.
- Can capture a pulse if the input event source is faster than the target clock.
- Synchronization of input event and target clock.
- Single-cycle pulse generation for target.

7.10 On-chip static RAM

The LPC435x/3x/2x/1x support up to 136 kB SRAM with separate bus master access for higher throughput and individual power control for low power operation.

7.11 On-chip flash memory

The LPC435x/3x/2x/1x contain up to 1 MB of dual-bank flash program memory. With dual-bank flash memory, the user code can write or erase one flash bank while reading the other flash bank without interruption. A two-port flash accelerator maximizes the flash performance.

In-System Programming (ISP) and In-Application Programming (IAP) routines for programming the flash memory are provided in the Boot ROM.

7.12 EEPROM

The LPC435x/3x/2x/1x contain 16 kB of on-chip byte-erasable and byte-programmable EEPROM memory.

The EEPROM memory is divided into 128 pages. The user can access pages 1 through 127. Page 128 is protected.

7.13 Boot ROM

The internal ROM memory is used to store the boot code of the LPC435x/3x/2x/1x. After a reset, the ARM processor will start its code execution from this memory.

The boot ROM memory includes the following features:

- The ROM memory size is 64 kB.
- Supports booting from external static memory such as NOR flash, SPI flash, quad SPI flash, USB0, and USB1.
- Includes API for OTP programming.
- Includes a flexible USB device stack that supports Human Interface Device (HID), Mass Storage Class (MSC), and Device Firmware Upgrade (DFU) drivers.

Table 6. EMC pinout for different packages

Function	LBGA256	TFBGA100	LQFP208	LQFP144
$\overline{OE}$	$\overline{EMC\_OE}$	$\overline{EMC\_OE}$	$\overline{EMC\_OE}$	$\overline{EMC\_OE}$
$\overline{WE}$	$\overline{EMC\_WE}$	$\overline{EMC\_WE}$	$\overline{EMC\_WE}$	$\overline{EMC\_WE}$
CKEOUT	EMC_ CKEOUT[3:0]	EMC_ CKEOUT[1:0]	EMC_ CKEOUT[1:0]	EMC_ CKEOUT[1:0]
CLK	EMC_CLK[3:0]; EMC_CLK01, EMC_CLK23	EMC_CLK0, EMC_CLK3; EMC_CLK01, EMC_CLK23	EMC_CLK0, EMC_CLK3; EMC_CLK01, EMC_CLK23	EMC_CLK0, EMC_CLK3; EMC_CLK01, EMC_CLK23
DQMOUT	EMC_ DQMOUT[3:0]	-	EMC_ DQMOUT[1:0]	EMC_ DQMOUT[1:0]
$\overline{DYCS}$	$\overline{EMC\_DYCS[3:0]}$	$\overline{EMC\_DYCS[1:0]}$	$\overline{EMC\_DYCS[2:0]}$	$\overline{EMC\_DYCS[1:0]}$
$\overline{CAS}$	$\overline{EMC\_CAS}$	$\overline{EMC\_CAS}$	$\overline{EMC\_CAS}$	$\overline{EMC\_CAS}$
$\overline{RAS}$	$\overline{EMC\_RAS}$	$\overline{EMC\_RAS}$	$\overline{EMC\_RAS}$	$\overline{EMC\_RAS}$

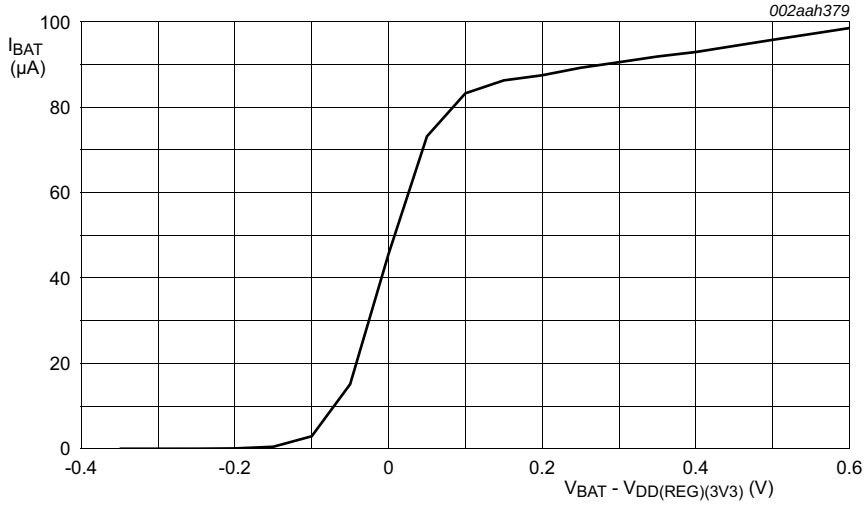
7.18.4.1 Features

- Dynamic memory interface support including single data rate SDRAM.
- Asynchronous static memory device support including RAM, ROM, and NOR flash, with or without asynchronous page mode.
- Low transaction latency.
- Read and write buffers to reduce latency and to improve performance.
- 8/16/32 data and 24 address lines wide static memory support.
- 16 bit and 32 bit wide chip select SDRAM memory support.
- Static memory features include:
  - Asynchronous page mode read
  - Programmable Wait States
  - Bus turnaround delay
  - Output enable and write enable delays
  - Extended wait
- Four chip selects for synchronous memory and four chip selects for static memory devices.
- Power-saving modes dynamically control EMC_CKEOUT and EMC_CLK signals to SDRAMs.
- Dynamic memory self-refresh mode controlled by software.
- Controller supports 2048 (A0 to A10), 4096 (A0 to A11), and 8192 (A0 to A12) row address synchronous memory parts. Those are typically 512 MB, 256 MB, and 128 MB parts, with 4, 8, 16, or 32 data bits per device.
- Separate reset domains allow the for auto-refresh through a chip reset if desired.
- SDRAM clock can run at full or half the Cortex-M4 core frequency.

Note: Synchronous static memory devices (synchronous burst mode) are not supported.

Table 11. Static characteristics *…continued*
T_{amb} = −40 °C to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
V_{OH}	HIGH-level output voltage	I_{OH} = −8 mA		$V_{DD(IO)}$ − 0.4	-	-	V
V_{OL}	LOW-level output voltage	I_{OL} = 8 mA		-	-	0.4	V
I_{OH}	HIGH-level output current	$V_{OH} = V_{DD(IO)} - 0.4$ V		−8	-	-	mA
I_{OL}	LOW-level output current	V_{OL} = 0.4 V		8	-	-	mA
I_{OHS}	HIGH-level short-circuit output current	drive HIGH; connected to ground	[11]	-	-	86	mA
I_{OLS}	LOW-level short-circuit output current	drive LOW; connected to $V_{DD(IO)}$	[11]	-	-	76	mA
I_{pd}	pull-down current	$V_I = V_{DD(IO)}$	[13] [14] [15]	-	62	-	μA
I_{pu}	pull-up current	V_I = 0 V	[13] [14] [15]	-	−62	-	μA
		$V_{DD(IO)} < V_I \leq 5$ V		-	0	-	μA
Open-drain I^2C0-bus pins							
V_{IH}	HIGH-level input voltage			0.7 × $V_{DD(IO)}$	-	-	V
V_{IL}	LOW-level input voltage			−0.5	0.14	0.3 × $V_{DD(IO)}$	V
V_{hys}	hysteresis voltage			0.1 × $V_{DD(IO)}$	-	-	V
V_{OL}	LOW-level output voltage	I_{OLS} = 3 mA		-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{DD(IO)}$	[12]	-	4.5	-	μA
		V_I = 5 V		-	-	10	μA
Oscillator pins							
$V_{i(XTAL1)}$	input voltage on pin XTAL1			−0.5	-	1.2	V
$V_{o(XTAL2)}$	output voltage on pin XTAL2			−0.5	-	1.2	V
C_{io}	input/output capacitance		[16]	-	-	0.8	pF
USB0 pins[17]							
V_I	input voltage	on pins USB0_DP; USB0_DM; USB0_VBUS					
		$V_{DD(IO)} \geq 2.4$ V		0	-	5.25	V
		$V_{DD(IO)}$ = 0 V		0	-	3.6	V
R_{pd}	pull-down resistance	on pin USB0_VBUS		48	64	80	kΩ



Conditions: $V_{DD(REG)(3V3)}$ = 3.0 V; V_{BAT} = 2.6 V to 3.6 V; CCLK = 12 MHz.

Remark: The recommended operating condition for the battery supply is $V_{DD(REG)(3V3)} > V_{BAT} + 0.2$ V.

Fig 19. Typical battery supply current in Active mode

10.2 Peripheral power consumption

The typical power consumption at T = 25 °C for each individual peripheral is measured as follows:

1. Enable all branch clocks and measure the current $I_{DD(REG)(3V3)}$.
2. Disable the branch clock to the peripheral to be measured and keep all other branch clocks enabled.
3. Calculate the difference between measurement 1 and 2. The result is the peripheral power consumption.

Table 12. Peripheral power consumption

Peripheral	Branch clock	$I_{DD(REG)(3V3)}$ in mA	
		Branch clock frequency = 48 MHz	Branch clock frequency = 96 MHz
M0 core	CLK_M4_M0APP	3.3	6.6
I2C1	CLK_APB3_I2C1	0.01	0.01
I2C0	CLK_APB1_I2C0	< 0.01	0.02
DAC	CLK_APB3_DAC	0.01	0.02
ADC0	CLK_APB3_ADC0	0.07	0.07
ADC1	CLK_APB3_ADC1	0.07	0.07
CAN0	CLK_APB3_CAN0	0.17	0.17
CAN1	CLK_APB1_CAN1	0.16	0.15
MOTOCON	CLK_APB1_MOTOCON	0.04	0.04
I2S	CLK_APB1_I2S	0.09	0.08
SPIFI	CLK_SPIFI, CLK_M4_SPIFI	1.14	2.29

11.4 Crystal oscillator

Table 19. Dynamic characteristic: oscillator

T_{amb} = −40 °C to +105 °C; $V_{DD(IO)}$ over specified ranges; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V.[1]

Symbol	Parameter	Conditions		Min	Typ[2]	Max	Unit
Low-frequency mode (1-20 MHz)[5]							
$t_{jit(per)}$	period jitter time	5 MHz crystal	[3][4]	-	13.2	-	ps
		10 MHz crystal		-	6.6	-	ps
		15 MHz crystal		-	4.8	-	ps
High-frequency mode (20 - 25 MHz)[6]							
$t_{jit(per)}$	period jitter time	20 MHz crystal	[3][4]	-	4.3	-	ps
		25 MHz crystal		-	3.7	-	ps

[1] Parameters are valid over operating temperature range unless otherwise specified.

[2] Typical ratings are not guaranteed. The values listed are at room temperature (25 °C), nominal supply voltages.

[3] Indicates RMS period jitter.

[4] PLL-induced jitter is not included.

[5] Select HF = 0 in the XTAL_OSC_CTRL register.

[6] Select HF = 1 in the XTAL_OSC_CTRL register.

11.5 IRC oscillator

Table 20. Dynamic characteristic: IRC oscillator

2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$f_{osc(RC)}$	internal RC oscillator frequency	-40 °C ≤ T_{amb} < 0 °C	12.0 - 3 %	12.0	12.0 + 3 %	MHz
		0 °C ≤ T_{amb} ≤ 85 °C	12.0 - 1.5 %	12.0	12.0 + 1.5 %	MHz
		85 °C < T_{amb} < 105 °C	12.0 - 3 %	12.0	12.0 + 3 %	MHz

[1] Typical ratings are not guaranteed. The values listed are at room temperature (25 °C), nominal supply voltages.

11.6 RTC oscillator

See Section 13.3 for connecting the RTC oscillator to an external clock source.

Table 21. Dynamic characteristic: RTC oscillator

T_{amb} = −40 °C to +105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V or 2.4 V ≤ V_{BAT} ≤ 3.6 V[1]

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
f_i	input frequency	-		-	32.768	-	kHz
$I_{CC(osc)}$	oscillator supply current				280	800	nA

[1] Parameters are valid over operating temperature range unless otherwise specified.

11.17 External memory interface

Table 31. Dynamic characteristics: Static asynchronous external memory interface

C_L = 22 pF for EMC_Dn C_L = 20 pF for all others; T_{amb} = −40 °C to 105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V; values guaranteed by design; the values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. Timing parameters are given for single memory access cycles. In a normal read operation, the EMC changes the address while CS is asserted which results in multiple memory accesses.

Symbol	Parameter[1]	Conditions		Min	Typ	Max	Unit
Read cycle parameters							
t_{CSLAV}	$\overline{CS}$ LOW to address valid time			−3.1	-	1.6	ns
t_{CSLOEL}	$\overline{CS}$ LOW to $\overline{OE}$ LOW time		[2] [2]	−0.6 + $T_{cy(clk)}$ × WAITOEN	-	1.3 + $T_{cy(clk)}$ × WAITOEN	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW time	PB = 1		−0.7	-	1.8	ns
t_{OELOEH}	$\overline{OE}$ LOW to $\overline{OE}$ HIGH time		[2]	−0.6 + (WAITRD − WAITOEN + 1) × $T_{cy(clk)}$	-	−0.4 + (WAITRD − WAITOEN + 1) × $T_{cy(clk)}$	ns
t_{am}	memory access time			-	-	−16 + (WAITRD − WAITOEN +1) × $T_{cy(clk)}$	ns
$t_{h(D)}$	data input hold time			−16	-	-	ns
$t_{CSHBLSH}$	$\overline{CS}$ HIGH to $\overline{BLS}$ HIGH time	PB = 1		−0.4	-	1.9	ns
t_{CSHOEH}	CS HIGH to $\overline{OE}$ HIGH time			−0.4	-	1.4	ns
t_{OEHANV}	$\overline{OE}$ HIGH to address invalid	PB = 1		−2.0	-	2.6	ns
t_{CSHEOR}	$\overline{CS}$ HIGH to end of read time		[3]	−2.0	-	0	ns
t_{CSLSOR}	$\overline{CS}$ LOW to start of read time		[4]	0	-	1.8	ns
Write cycle parameters							
t_{CSLAV}	$\overline{CS}$ LOW to address valid time			−3.1	-	1.6	ns
t_{CSLDV}	$\overline{CS}$ LOW to data valid time			−3.1	-	1.5	ns
t_{CSLWEL}	$\overline{CS}$ LOW to $\overline{WE}$ LOW time	PB = 1		−1.5 + (WAITWEN + 1) × $T_{cy(clk)}$	-	0.2 + (WAITWEN + 1) × $T_{cy(clk)}$	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW time	PB = 1		−0.7	-	1.8	ns
t_{WELWEH}	$\overline{WE}$ LOW to $\overline{WE}$ HIGH time	PB = 1	[2]	−0.6 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	-	−0.4 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	ns
t_{WEHDNV}	$\overline{WE}$ HIGH to data invalid time	PB = 1	[2]	−0.9 + $T_{cy(clk)}$	-	2.3 + $T_{cy(clk)}$	ns
t_{WEHEOW}	$\overline{WE}$ HIGH to end of write time	PB = 1	[2] [5]	−0.4 + $T_{cy(clk)}$	-	−0.3 + $T_{cy(clk)}$	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW	PB = 0		−0.7 + (WAITWEN + 1) × $T_{cy(clk)}$	-	1.8 + (WAITWEN + 1) × $T_{cy(clk)}$	ns

Table 31. Dynamic characteristics: Static asynchronous external memory interface *…continued*

C_L = 22 pF for EMC_Dn C_L = 20 pF for all others; T_{amb} = −40 °C to 105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V; values guaranteed by design; the values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. Timing parameters are given for single memory access cycles. In a normal read operation, the EMC changes the address while CS is asserted which results in multiple memory accesses.

Symbol	Parameter[1]	Conditions		Min	Typ	Max	Unit
$t_{BLSLBLSH}$	$\overline{BLS}$ LOW to $\overline{BLS}$ HIGH time	PB = 0	[2]	−0.9 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	-	−0.1 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	ns
$t_{BLSHEOW}$	$\overline{BLS}$ HIGH to end of write time	PB = 0	[2] [5]	−1.9 + $T_{cy(clk)}$	-	−0.5 + $T_{cy(clk)}$	ns
$t_{BLSHDNV}$	$\overline{BLS}$ HIGH to data invalid time	PB = 0	[2]	−2.5 + $T_{cy(clk)}$	-	1.4 + $T_{cy(clk)}$	ns
t_{CSHEOW}	$\overline{CS}$ HIGH to end of write time		[5]	−2.0	-	0	ns
$t_{BLSHDNV}$	$\overline{BLS}$ HIGH to data invalid time	PB = 1		−2.5	-	1.4	ns
t_{WEHANV}	WE HIGH to address invalid time	PB = 1		−0.9 + $T_{cy(clk)}$	-	2.4 + $T_{cy(clk)}$	ns

[1] Parameters specified for 40 % of $V_{DD(IO)}$ for rising edges and 60 % of $V_{DD(IO)}$ for falling edges.

[2] $T_{cy(clk)}$ = 1/CCLK (see LPC43xx User manual).

[3] End Of Read (EOR): longest of t_{CSHOEH}, t_{OEHANV}, $t_{CSHBLSH}$.

[4] Start Of Read (SOR): longest of t_{CSLAV}, t_{CSLOEL}, $t_{CSLBLSL}$.

[5] End Of Write (EOW): earliest of address not valid or $\overline{EMC\_BLSn}$ HIGH.

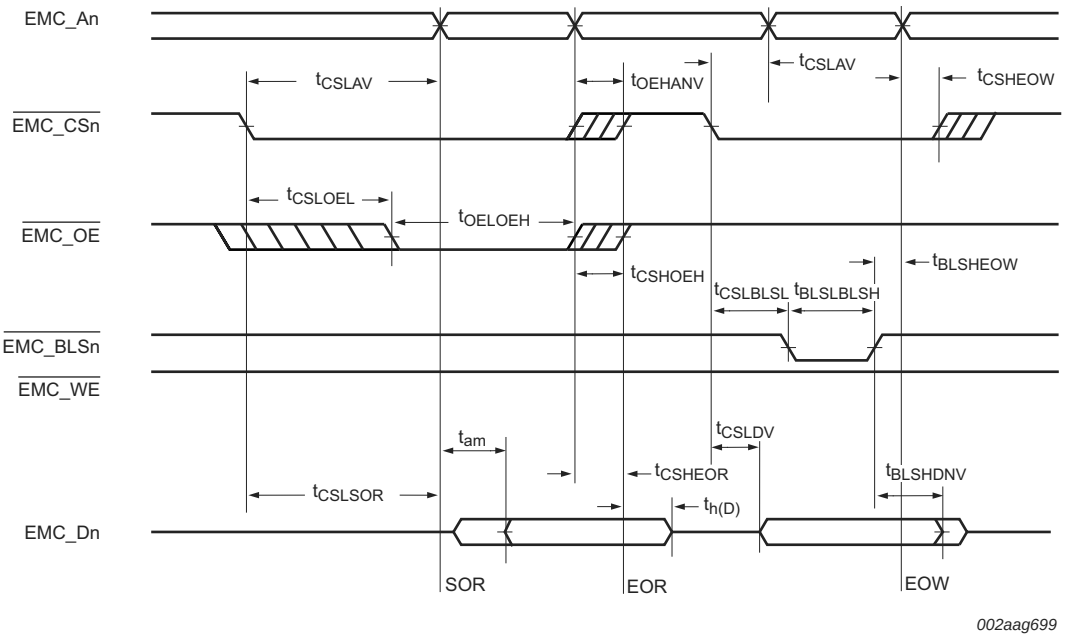


Fig 35. External static memory read/write access (PB = 0)

Table 42. LCD panel connections for STN dual panel mode

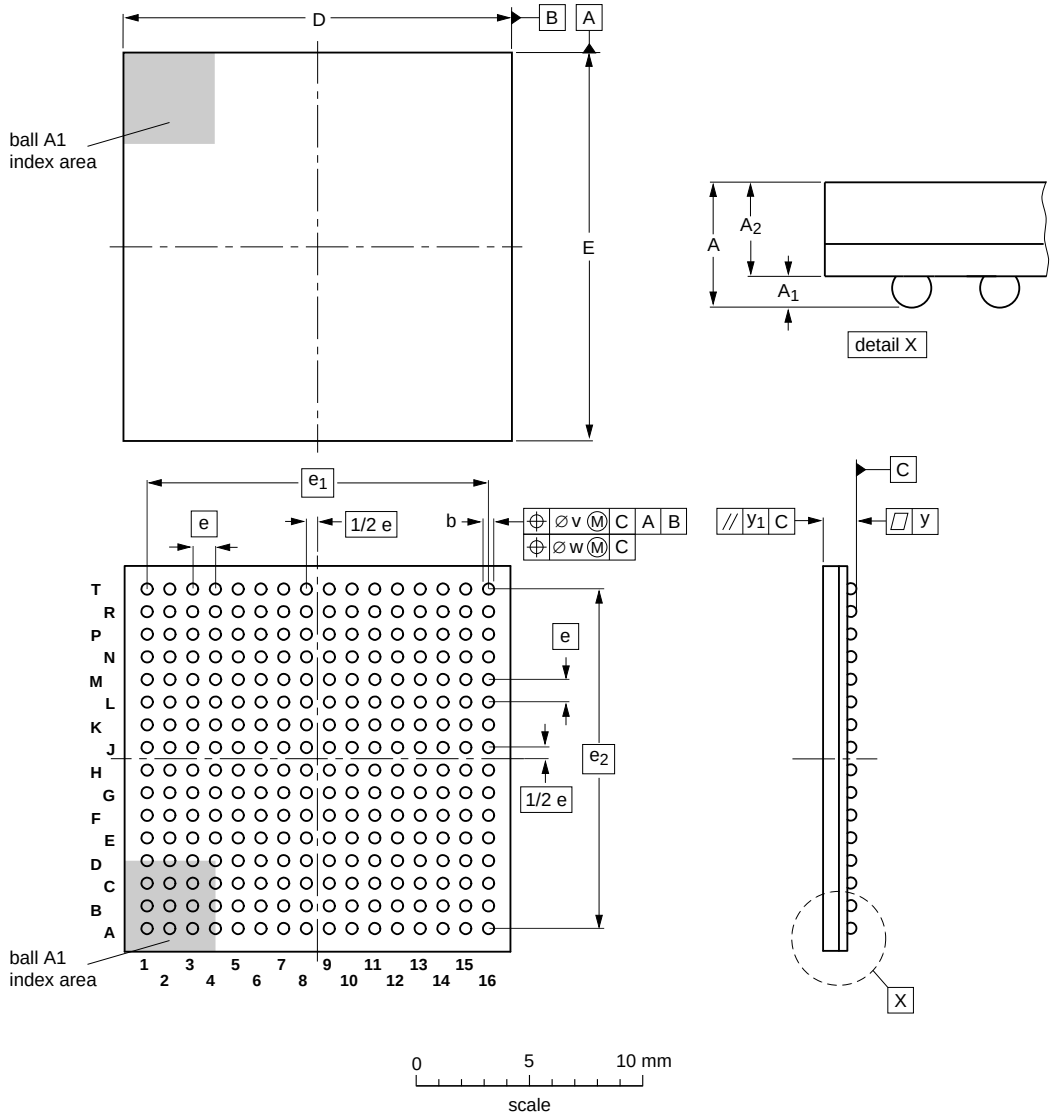
External pin	4-bit mono STN dual panel		8-bit mono STN dual panel		Color STN dual panel	
	LPC43xx pin used	LCD function	LPC43xx pin used	LCD function	LPC43xx pin used	LCD function
LCD_VD2	P4_3	UD[2]	P4_3	UD[2]	P4_3	UD[2]
LCD_VD1	P4_4	UD[1]	P4_4	UD[1]	P4_4	UD[1]
LCD_VD0	P4_1	UD[0]	P4_1	UD[0]	P4_1	UD[0]
LCD_LP	P7_6	LCDLP	P7_6	LCDLP	P7_6	LCDLP
LCD_ENAB/ LCDM	P4_6	LCDENAB/ LCDM	P4_6	LCDENAB/ LCDM	P4_6	LCDENAB/ LCDM
LCD_FP	P4_5	LCDFP	P4_5	LCDFP	P4_5	LCDFP
LCD_DCLK	P4_7	LCDDCLK	P4_7	LCDDCLK	P4_7	LCDDCLK
LCD_LE	P7_0	LCDLE	P7_0	LCDLE	P7_0	LCDLE
LCD_PWR	P7_7	LCDPWR	P7_7	LCDPWR	P7_7	LCDPWR
GP_CLKIN	PF_4	LCDCLKIN	PF_4	LCDCLKIN	PF_4	LCDCLKIN

Table 43. LCD panel connections for TFT panels

External pin	TFT 12 bit (4:4:4 mode)		TFT 16 bit (5:6:5 mode)		TFT 16 bit (1:5:5:5 mode)		TFT 24 bit	
	LPC43xx pin used	LCD function	LPC43xx pin used	LCD function	LPC43xx pin used	LCD function	LPC43xx pin used	LCD function
LCD_VD23	PB_0	BLUE3	PB_0	BLUE4	PB_0	BLUE4	PB_0	BLUE7
LCD_VD22	PB_1	BLUE2	PB_1	BLUE3	PB_1	BLUE3	PB_1	BLUE6
LCD_VD21	PB_2	BLUE1	PB_2	BLUE2	PB_2	BLUE2	PB_2	BLUE5
LCD_VD20	PB_3	BLUE0	PB_3	BLUE1	PB_3	BLUE1	PB_3	BLUE4
LCD_VD19	-	-	P7_1	BLUE0	P7_1	BLUE0	P7_1	BLUE3
LCD_VD18	-	-	-	-	P7_2	intensity	P7_2	BLUE2
LCD_VD17	-	-	-	-	-	-	P7_3	BLUE1
LCD_VD16	-	-	-	-	-	-	P7_4	BLUE0
LCD_VD15	PB_4	GREEN3	PB_4	GREEN5	PB_4	GREEN4	PB_4	GREEN7
LCD_VD14	PB_5	GREEN2	PB_5	GREEN4	PB_5	GREEN3	PB_5	GREEN6
LCD_VD13	PB_6	GREEN1	PB_6	GREEN3	PB_6	GREEN2	PB_6	GREEN5
LCD_VD12	P8_3	GREEN0	P8_3	GREEN2	P8_3	GREEN1	P8_3	GREEN4
LCD_VD11	-	-	P4_9	GREEN1	P4_9	GREEN0	P4_9	GREEN3
LCD_VD10	-	-	P4_10	GREEN0	P4_10	intensity	P4_10	GREEN2
LCD_VD9	-	-	-	-	-	-	P4_8	GREEN1
LCD_VD8	-	-	-	-	-	-	P7_5	GREEN0
LCD_VD7	P8_4	RED3	P8_4	RED4	P8_4	RED4	P8_4	RED7
LCD_VD6	P8_5	RED2	P8_5	RED3	P8_5	RED3	P8_5	RED6
LCD_VD5	P8_6	RED1	P8_6	RED2	P8_6	RED2	P8_6	RED5
LCD_VD4	P8_7	RED0	P8_7	RED1	P8_7	RED1	P8_7	RED4
LCD_VD3	-	-	P4_2	RED0	P4_2	RED0	P4_2	RED3
LCD_VD2	-	-	-	-	P4_3	intensity	P4_3	RED2
LCD_VD1	-	-	-	-	-	-	P4_4	RED1

14. Package outline

LBGA256: plastic low profile ball grid array package; 256 balls; body 17 x 17 x 1 mm **SOT740-2**



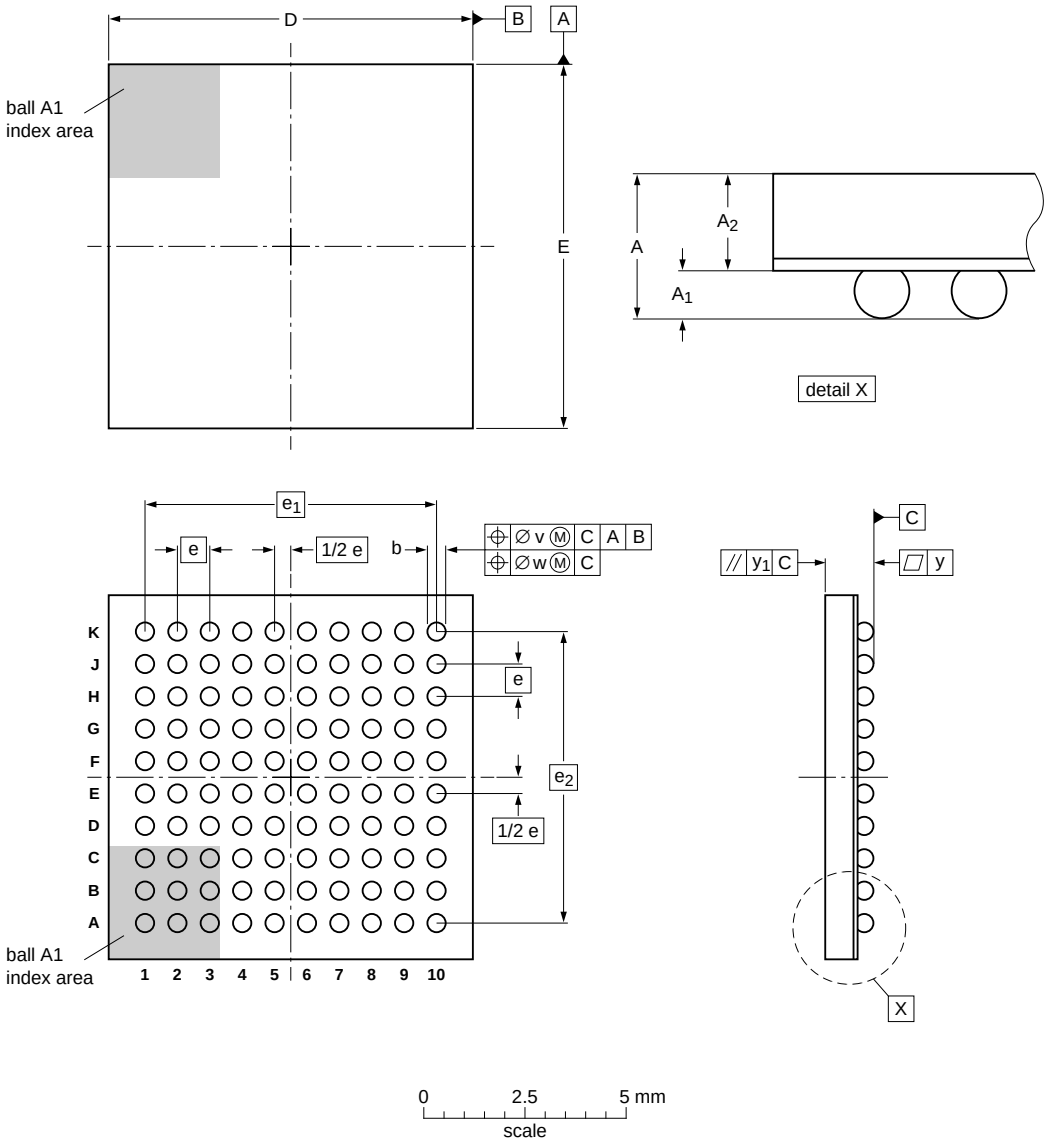
DIMENSIONS (mm are the original dimensions)

UNIT	A max	A_1	A_2	b	D	E	e	e_1	e_2	v	w	y	y_1
mm	1.55	0.45 0.35	1.1 0.9	0.55 0.45	17.2 16.8	17.2 16.8	1	15	15	0.25	0.1	0.12	0.35

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT740-2	- - -	MO-192	- - -			~~05-06-16~~ 05-08-04

Fig 51. Package outline LBGA256 package

TFBGA100: plastic thin fine-pitch ball grid array package; 100 balls; body 9 x 9 x 0.7 mm **SOT926-1**



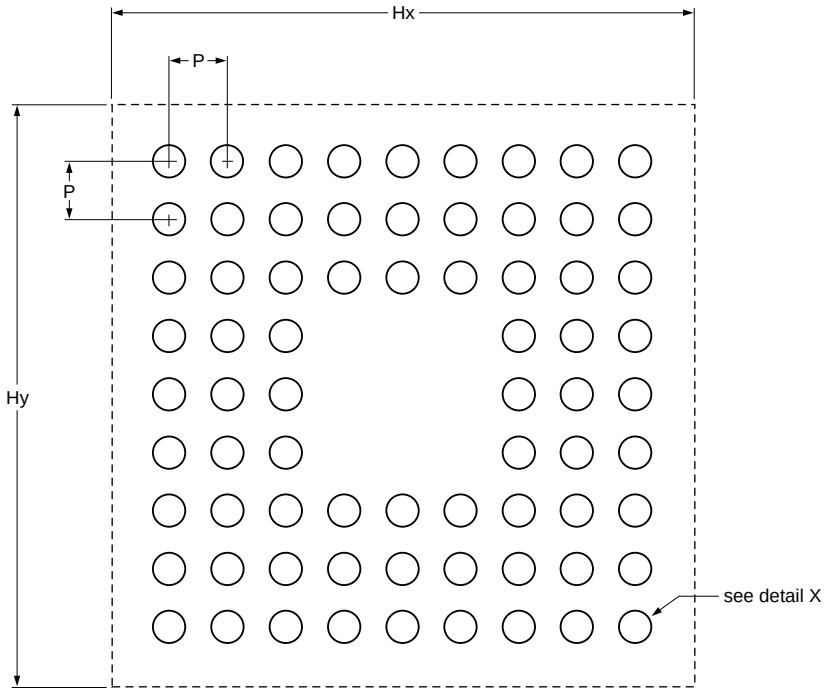
DIMENSIONS (mm are the original dimensions)

UNIT	A max	A_1	A_2	b	D	E	e	e_1	e_2	v	w	y	y_1
mm	1.2	0.4 0.3	0.8 0.65	0.5 0.4	9.1 8.9	9.1 8.9	0.8	7.2	7.2	0.15	0.05	0.08	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT926-1	- - -	- - -	- - -			~~05-12-09~~ 05-12-22

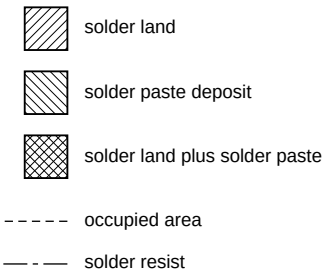
Fig 53. Package outline of the TFBGA100 package

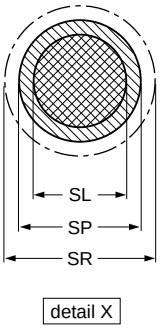
Footprint information for reflow soldering of TFBGA100 package **SOT926-1**



Generic footprint pattern

Refer to the package outline drawing for actual layout





detail X

DIMENSIONS in mm

P	SL	SP	SR	Hx	Hy
0.80	0.330	0.400	0.480	9.400	9.400

sot926-1_fr

Fig 58. Reflow soldering of the TFBGA100 package

Table 47. Revision history *…continued*

Document ID	Release date	Data sheet status	Change notice	Supersedes
Modifications:	• Updated Section 1 “General description”. • Minimum operating voltage changed from 2.2 V to 2.4 V for $V_{DD(REG)(3V3)}$, $V_{DD(IO)}$, $V_{DDA(3V3)}$, V_{BAT} in Table 11. • Operating temperature corrected in Table 27. Tamb = T_{amb} = -40 °C to 105 °C. • Max and min values of parameters t_{lag} and t_{lead} corrected for SSP master mode in Table 27. • Figure 32 “SSP in SPI mode and SPI slave timing” updated. • Typical values for parameters t_{DS}, t_{DH}, $t_{v(Q)}$, $t_{h(Q)}$ for SSP slave mode replaced by min and max numbers in Table 25. • Parameters t_{lead}, t_{lag}, and t_d added to SSP slave mode in Table 27. • SPIFI timing data restated for CL = 20 pF in Table 29 “Dynamic characteristics: SPIFI”. • USART timing added for master and slave mode in Figure 30 “USART timing”. • USB0_VBUS changed to input only. See Table 3 “Pin description”. • Changed the flash erase time (t_{er}) to 100ms. See Table 15. • Updated Dynamic characteristics: SD/MMC table. See Table 37. • Added Band gap characteristics table. See Table 14. • Updated Table 2: Motor control PWM instead of PWM. • Updated Dynamic characteristics: USB0 and USB1 pins (full-speed). See Table 34. • Added a table note: The values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. See Table 31. • Added a remark to Table 34. • Updated Table 13 “BOD static characteristics[1]”. Removed BOD interrupt levels 0 and 1; removed Reset levels 0 and 1. Not applicable.			
LPC435X_3X_2X_1X v.4	20140819	Product data sheet	-	LPC435X_3X_2X_1X v.3

Table 47. Revision history *…continued*

Document ID	Release date	Data sheet status	Change notice	Supersedes
LPC4357_53_37_33 v.2	20120711	Preliminary data sheet	-	LPC4357_53 v.1
Modifications:	• Data sheet status changed to preliminary. • Parts LPC4337 and LPC4333 added. • Minimum value of V_I for conditions “USB0 pins USB0_DP; USB0_DM; USB0_VBUS”, “USB0 pins USB0_ID; USB0_RREF”, and “USB1 pins USB1_DP and USB1_DM” changed to −0.3 V in Table 6. • Section 10.2 added. • Table 8 “Thermal resistance (LQFP packages)” and Table 9 “Thermal resistance value (BGA packages)” added. • AES removed. Available on parts LPC43Sxx only. • Dynamic characteristics of the SD/MMC controller updated in Table 30. • Dynamic characteristics of the LCD controller updated in Table 31. • Dynamic characteristics of the SSP controller updated in Table 23. • Parameters I_{IL} and I_{IH} renamed to I_{LL} and I_{LH} in Table 10.			
LPC4357_53 v.1	20120604	Objective data sheet	-	-